FUJITSU SEMICONDUCTOR
DATA SHEET

DS405-00010-1v0-E

ASSP

High Power Factor LED Driver IC for LED lighting

MB39C602

■ DESCRIPTION

MB39C602 is a flyback type switching regulator contorller IC. The LED current is regulated by controlling the switching on-time depending on the LED load.
It is most suitable for the general lighting applications, for example stocks of commercial and residential light bulbs and so on.

■ FEATURES

- High power factor in Single Conversion
- Helps to achieve high efficiency and low EMI by detecting auxiliary transformer zero current
- Switching frequency setting depend on the FC pin current : 30 kHz to 120 kHz
- Control of the current of Primary Winding without the external sense resistor
- Built-in under voltage lock out function
- Built-in output over voltage protection function
- Built-in over temperature protection function
- Input voltage range VDD : 9V to 20V
- Input voltage range for LED lighting applications : $AC110V_{RMS}$, $AC230V_{RMS}$
- Package : SOP-8 (3.9mm × 5.05mm × 1.75mm [Max])

■ APPLICATIONS

- LED lighting
- PWM dimmable LED lighting etc.

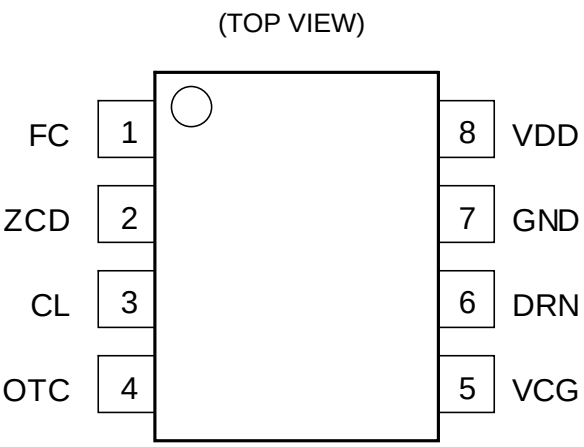
Power Supply online Design Simulation
Easy DesignSim

This product supports the web-based design simulation tool.
It can easily select external components and can display useful information.
Please access from the following URL.

http://edevice.fujitsu.com/pmic/en-easy/?m=ds

2012.12

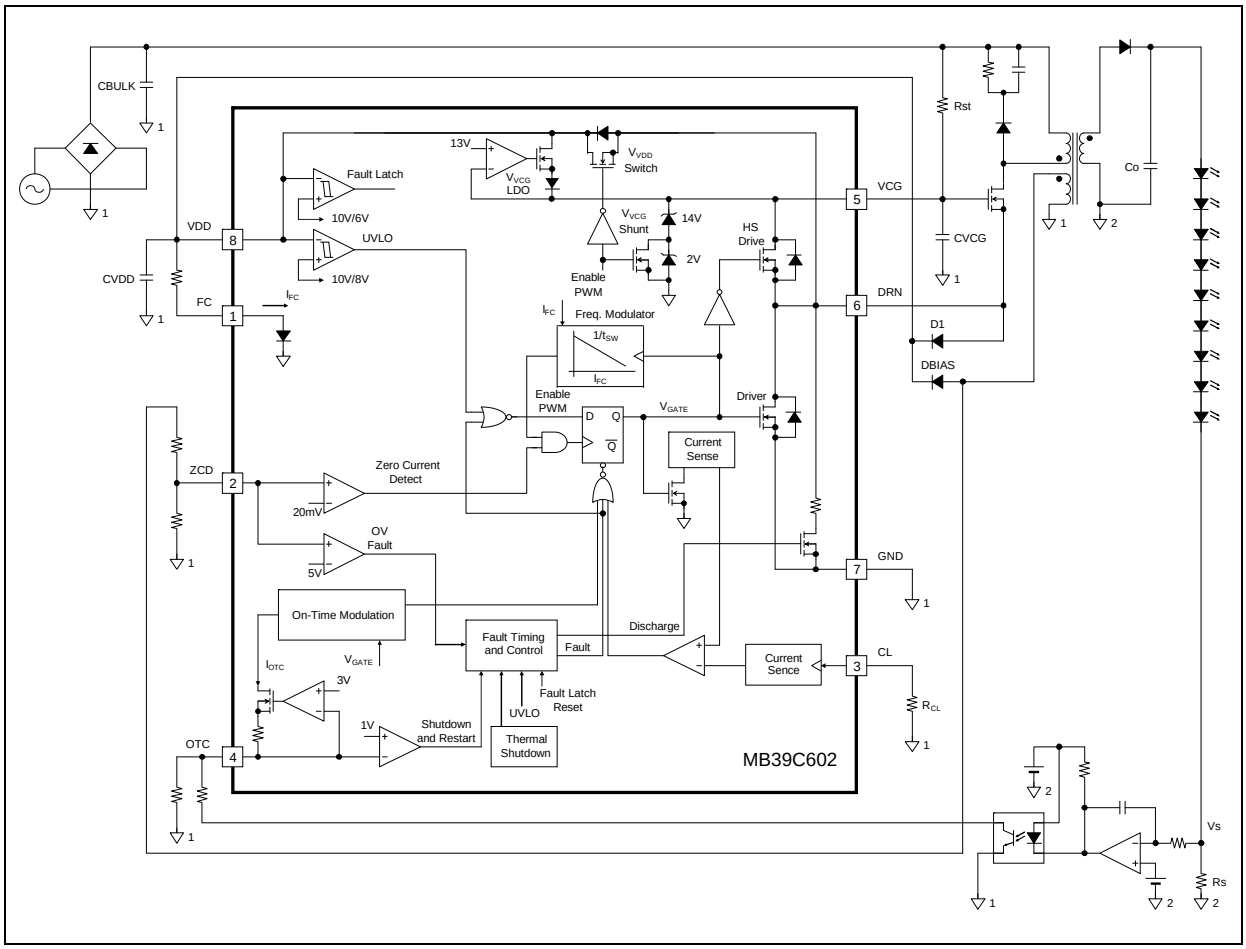
■ PIN ASSIGNMENT



■ PIN DESCRIPTIONS

Pin No.	Pin Name	I/O	Description
1	FC	I	Switching frequency setting pin.
2	ZCD	I	Transformer auxiliary winding zero current detecting pin.
3	CL	I	Pin for controlling peak current of transformer primary winding.
4	OTC	I	On-time control pin.
5	VCG	-	External MOSFET gate bias pin.
6	DRN	O	External MOSFET source connection pin.
7	GND	-	Ground pin.
8	VDD	-	Power supply pin.

■BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Condition	Rating		Unit
			Min	Max	
Power supply voltage	V_{VDD}	VDD pin	-0.3	+25.0	V
Input voltage	V_{DRN}	DRN pin	-	20	V
	V_{VCG}	VCG pin	-0.3	+16.0	V
	V_{ZCD}	ZCD pin	-0.3	+6.0	V
	V_{OTC}	OTC pin	-0.3	+6.0	V
	V_{CL}	CL pin	-0.3	+6.0	V
	V_{FC}	FC pin	-0.3	+2.0	V
Input current	I_{VCG}	VCG pin	-	10	mA
	I_{OTC}	OTC pin	-1	0	mA
	I_{CL}	CL pin	-1	0	mA
	I_{FC}	FC pin	0	1	mA
Output current	I_{DRN}	DRN pin	-	800	mA
	I_{DRN}	DRN pin, Pulsed 400ns, 2% duty cycle	-1.5	+6.0	A
Power dissipation	P_D	Ta ≤ +25°C	-	800*	mW
Storage temperature	T_{STG}		-55	+125	°C

*: The value when using two layers PCB.
Reference: θja (wind speed 0m/s): +125°C/W

WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

■ RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Condition	Value			Unit
			Min	Typ	Max	
VDD pin input voltage	VDD	VDD pin	9	-	20	V
VCG pin input voltage	VCG	VCG pin (from low-impedance source)	9	-	13	V
VCG pin input current	I_{VCG}	VCG pin (from high-impedance source)	10	-	2000	µA
OTC pin resistance to GND	R_{OTC}	OTC pin	25	-	100	kΩ
CL pin resistance to GND	R_{CL}	CL pin	24.3	-	200.0	kΩ
ZCD pin resistance to auxiliary winding	R_{ZCD}	ZCD pin Transformer auxiliary winding connection resistor	50	-	200	kΩ
VCG pin capacitance to GND	C_{VCG}	VCG pin	33	-	200	nF
VDD pin bypass capacitance	C_{BP}	Ceramic capacitance to set between VDD and GND pin	0.1	-	1.0	µF
Operating ambient temperature	Ta	-	-40	+25	+85	°C

WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.
Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure. No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their representatives beforehand.

■ELECTRICAL CHARACTERISTICS

(Ta = +25°C, V_{VDD} = 12V)

Parameter		Symbol	Pin No.	Condition	Value			Unit
					Min	Typ	Max	
VDD and VCG SUPPLY	VCG voltage (Operating)	$VCG_{(OPERATING)}$	5	V_{VDD}=14V, I_{VCG}=2.0mA	13	14	15	V
	VCG voltage (Disable)	$VCG_{(DISABLED)}$	5	V_{OTC}=0V, I_{VCG}=26µA	15	16	17	V
	VCG voltage difference	ΔVCG	5	$VCG_{(DISABLED)}$ - $VCG_{(OPERATING)}$	1.75	2.00	2.15	V
	VCG Shunt input current	$I_{VCG\ (SREG)}$	5	V_{VCG}=$VCG_{(DISABLED)}$-100mV, V_{OTC}=0V	-	12	26	µA
	VCG Shunt Load Regulation	$\Delta VCG_{(SREG)}$	5	V_{OTC}=0V, 26µA<I_{VCG}≤5mA	-	125	200	mV
	VCG LDO regulation voltage	$VCG_{(LREG)}$	5	V_{VDD}=20V, I_{VCG}=-2mA	-	13	-	V
	VCG LDO Dropout voltage	$VCG_{(LREG, DO)}$	-	VDD-VCG, V_{VDD}=11V, I_{VCG}=-2mA	-	2.0	2.8	V
	UVLO Turn-on threshold voltage	$VDD_{(ON)}$	8	-	9.7	10.2	10.7	V
	UVLO Turn-off threshold voltage	$VDD_{(OFF)}$	8	-	7.55	8.00	8.50	V
	UVLO hysteresis	$\Delta VDD_{(UVLO)}$	8	$VDD_{(ON)}$ - $VDD_{(OFF)}$	1.9	2.2	2.5	V
	VDD switch on-resistance	$R_{DS,\ ON\ (VDD)}$	6,8	V_{VCG}=12V, V_{VDD}=7V, I_{DRN}=50mA	-	4*	10*	Ω
	Fault Latch Reset VDD voltage	$VDD_{(FAULT\ RESET)}$	8	-	5.6	6.0	6.4	V
MODULATION	Minimum switching period	$t_{SW\ (HF)}$	6	I_{FC}=5µA	7.215	7.760	8.305	µs
	Maximum switching period	$t_{SW\ (LF)}$	6	I_{FC}= 165µA	31.5*	35.0*	38.5*	µs
	DRN peak current	$I_{DRN\ (peak)}$	6	I_{FC}=5µA, I_{CL}=100µA	-	3*	-	A
			6	I_{FC}=5µA, I_{CL}=30µA	-	1*	-	A
	Minimum peak current for R_{CL} open	$I_{DRN\ (peak,\ absmin)}$	6	R_{CL}=OPEN	-	0.45*	-	A
	ILIM blanking time	$t_{BLANK\ (ILIM)}$	6	I_{FC}=5µA, R_{CL}=100kΩ, 1.2A pull-up on DRN	-	400*	-	ns
	CL voltage	V_{CL}	3	I_{FC}=5µA	2.94	3.00	3.06	V
	FC voltage	V_{FC}	1	I_{FC}=10µA	0.34	0.70	0.84	V
DRIVER	Driver on-resistance	$R_{DS\ (on)\ (DRN)}$	6,7	I_{DRN}=4.0A	-	200*	400*	mΩ
	Driver off leakage current	$I_{DRN\ (OFF)}$	6,7	V_{DRN}=12V	-	1.5	20.0	µA
	High-side driver on-resistance	$R_{DS\ (on)\ (HSDRV)}$	5,6	High-side driver current = 50mA	-	6*	11*	Ω
	DRN discharge current	I_{DIS}	6,7	VDD=OPEN, DRN=12V, Fault latch set	2.38	3.40	4.42	mA

Parameter		Symbol	Pin No.	Condition	Value			Unit
					Min	Typ	Max	
TRANSFORMER ZERO CURRENT DETECTION	Zero current threshold voltage	$V_{ZCD\ (TH)}$	2	-	5*	20*	50*	mV
	Clamp voltage	$V_{ZCD\ (CLAMP)}$	2	I_{ZCD}=-10µA	-200	-160	-100	mV
	Start timer operation threshold voltage	$V_{ZCD\ (START)}$	2	-	0.10	0.15	0.20	V
	Driver turn-on Delay time	$t_{DLY\ (ZCD)}$	6	150Ω pull-up 12V on DRN	-	150	-	ns
	Wait time for zero current detection	$t_{WAIT\ (ZCD)}$	6	-	2.0	2.4	2.8	µs
	Start timer period	t_{ST}	6	V_{ZCD}=0V	150	240	300	µs
OVERVOLTAGE FAULT	OVP threshold voltage	$V_{ZCD\ (OVP)}$	2	-	4.85	5.00	5.15	V
	OVP blanking time	$t_{BLANK,\ OVP}$	6	-	0.6	1.0	1.7	µs
	Input bias current	$I_{ZCD\ (bias)}$	2	V_{ZCD}=5V	-0.1	0	+0.1	µA
SHUTDOWN THRESHOLD	Shutdown Threshold voltage	$V_{OTC\ (Vth)}$	4	OTC= ↓	0.7	1.0	1.3	V
	Shutdown OTC current	$I_{OTC,\ PU}$	4	V_{OTC}= $V_{OTC\ (vth)}$	-600	-450	-300	µA
MAXIMUM ON TIME	ON-Time	t_{OTC}	6	R_{OTC}=76kΩ	3.4	3.8	4.2	µs
	OTC voltage	V_{OTC}	4	-	2.7	3.0	3.3	V
OTP	Shutdown temperature	T_{SD}	-	Tj, temperature rising	-	+150*	-	°C
	Hysteresis	T_{SD_HYS}	-	Tj, temperature falling,degrees below T_{SD}	-	+25*	-	°C
POWER SUPPLY CURRENT	Power supply current	$I_{VDD\ (STATIC)}$	8	V_{VDD}=20V, V_{ZCD}=1V	1.36	1.80	2.34	mA
		$I_{VDD\ (OPERATING)}$	8	V_{VDD}=20V	-	3.0*	3.7*	mA
	Power supply current for UVLO	$I_{VDD\ (UVLO)}$	8	V_{VDD}= $VDD_{(ON)}$ - 100mV	-	285	500	uA

*: Standard design value

■ FUNCTION EXPLANATION

(1) LED Current Control Function

MB39C602 is a flyback type switching regulator controller. The LED current is regulated by controlling the switching on-time depending on the LED load.The LED current is converted into detecting voltage (Vs) by sense resistor (Rs) connected in series with LED. Vs is compared by an external error amplifier (Err AMP).When Vs falls below a reference voltage, Err AMP output rises and the current that flows into the Opto-Coupler is decreased.

The OTC pin current is controlled via the Opto-Coupler in the on-time control block. In on-time control, it controls on-time at OTC pin current. So, on-time increases when the current of the OTC pin decreases. And the average current supplied to LED is regulated, because on-time is regulated at the constant switching frequency.

(2) Cascode Switching

The switch in Primary Winding is a cascode connection.The gate of external MOSFET is connected with the VCG pin, and the source is connected with the drain of internal Driver MOSFET. When the swich is on-state, internal Driver MOSFET is turned on, HS Driver MOSFET is turned off, and the source voltage of external MOSFET goes down to GND. For this period the DC bias is supplied to the gate of external MOSFET from the VCG pin. Therefore external MOSFET is turned on.

When the switch is off-state, internal Driver MOSFET is turned off, HS Driver MOSFET is turned on, and the source voltage of external MOSFET goes up to VCG voltage. For this period the DC bias is supplied to the gate of external MOSFET from the VCG pin. Therefore external MOSFET is turned off. Moreover, the current flowing into internal Driver MOSFET is equal to the current of Primary Winding. Therefore, the peak current into Primary Winding can be detected without the sense resistor.

(3) Natural PFC (Power Factor Correction) Function

In the AC voltage input, when the input current waveform is brought close to the sine-wave, and the phase difference is brought close to Zero, Power Factor is improved. In the flyback method operating in discontinuous conduction mode, when the input capacitance is set small, the input current almost becomes equal with peak current (I_{PEAK}) of Primary Winding.

$$I_{PEAK} = \left(\frac{V_{BULK} \times t_{ON}}{L_{MP}} \right) = \left(\frac{V_{BULK}}{\left(\frac{L_{MP}}{t_{ON}} \right)} \right)$$

V_{BULK} : Supply voltage of Primary Winding
L_{MP} : Inductance of Primary Winding
t_{ON} : On-time

In on-time control, if loop response of Error Amp. is set to lower than the AC frequency (below 1/10 of the AC frequency), on-time can be constant. Therefore, input current is proportional to input voltage, so Power Factor is regulated.

(4) Power-Up Sequencing

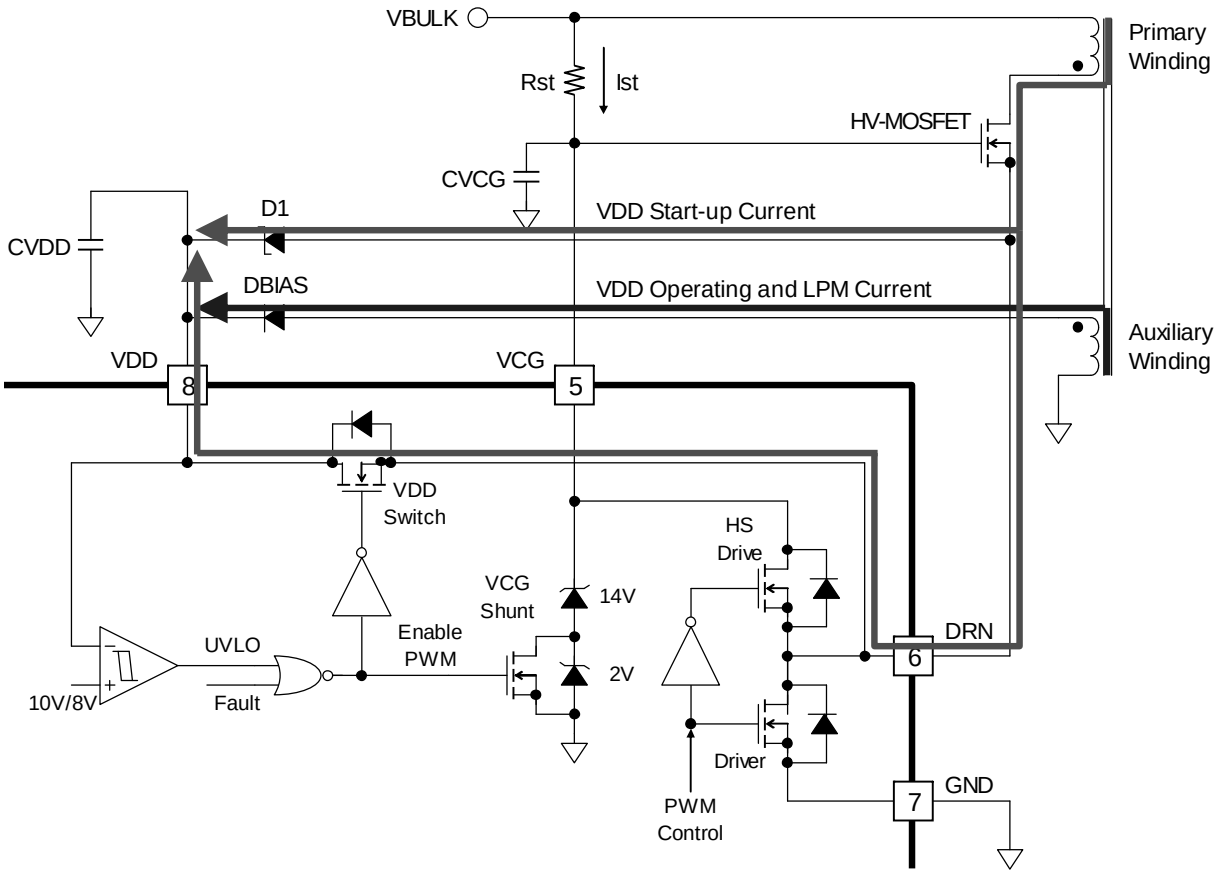
When the voltage is input to VBULK, the electric charge is charged to capacitance of the VCG pin (CVCG) through starting resistor (Rst). So, the voltage of the VCG pin rises. The voltage of the DRN pin rises by source follower when the voltage of the VCG pin reaches the threshold voltage of the external HVMOSFET.

The DRN pin is connected with the VDD pin through the internal VDD Switch, and VDD capacitor (CVDD) is charged from the DRN pin. When the voltage at the VDD pin reaches the threshold voltage of UVLO, the VDD Switch is turned off, and the internal Bias circuit operates, and the switching is started.

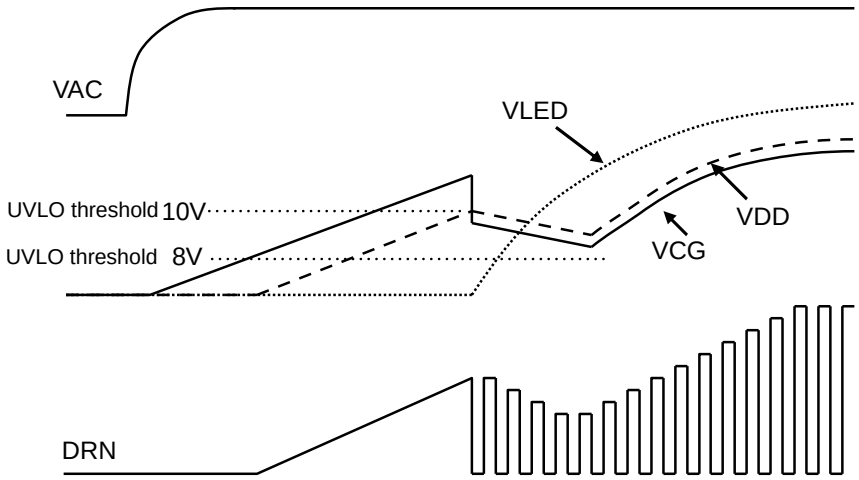
After the switching begins, the voltage at the VDD pin is supplied from Auxiliary Winding through the external diode (DBIAS). The voltage of an Auxiliary Winding is decided by rolling number ratio of Auxiliary Winding and Secondary Winding, and the voltage of Secondary Winding. Therefore, the voltage at the VDD pin is not supplied, until the voltage of Auxiliary Winding rises more than the voltage at the VDD pin. In this period, it is necessary to set the capacitor of the VDD pin to prevent the voltage of the VDD pin from falling below the threshold voltage of UVLO.

The external Schottky diode (D1) is required between the DRN pin and VDD pin. This diode is used to prevent the current that flows through the body diode of the VDD Switch.

- Current Passing When Starting



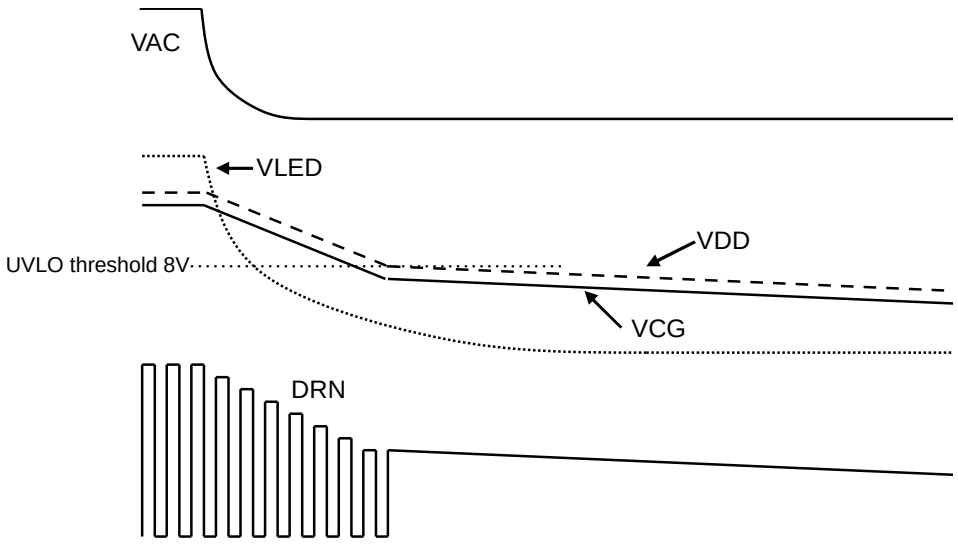
- Power-Up Sequencing



(5) Power Down Sequencing

When AC power is removed from the AC line, the current does not flow to Secondary Winding even if HV MOSFET is switching. The LED current is supplied from the output capacitance and decreases gradually. Similarly, the voltage at the VDD pin decreases because the current does not flow into Auxiliary Winding. The switching stops and MB39C602 becomes shutdown when the voltage at the VDD pin falls below the threshold voltage of UVLO.

- Power Down Sequencing

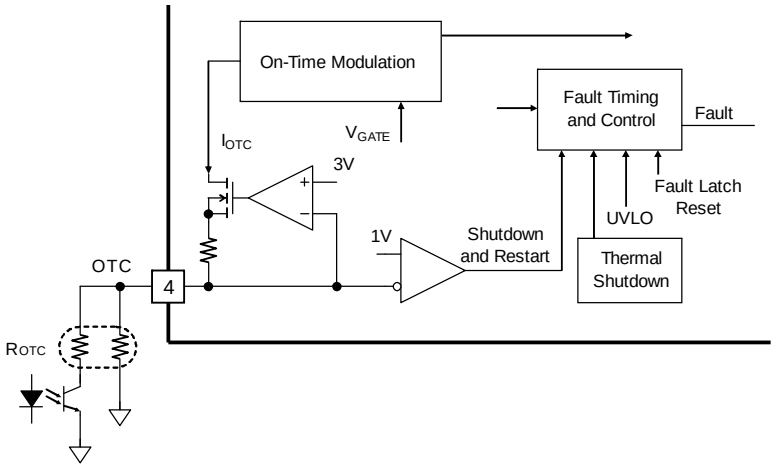


(6) OTC Part

It is set on-time by connecting resistance (R_{OTC}) with OTC pin.

As shown in following figure, the on-time can be controlled by connecting the collector of the Opto-Coupler through resistor from OTC.

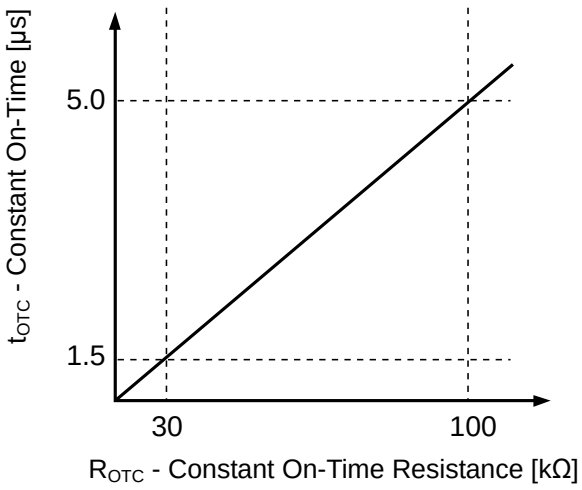
- OTC pin Control



The following figure shows how the on-time is programmed over the range of between 1.5µs and 5.0µs for either range of programming resistors. On-time is related to the programmed resistor based on the following equations.

$$R_{OTC} = t_{OTC} \times (2 \times 10^{10} \left[\frac{\Omega}{S} \right])$$

- On-time Setting Range



Moreover, it can be shutted down by making the voltage of the OTC pin below "$V_{OTC\ (Vth)}$ (typ 1V)".

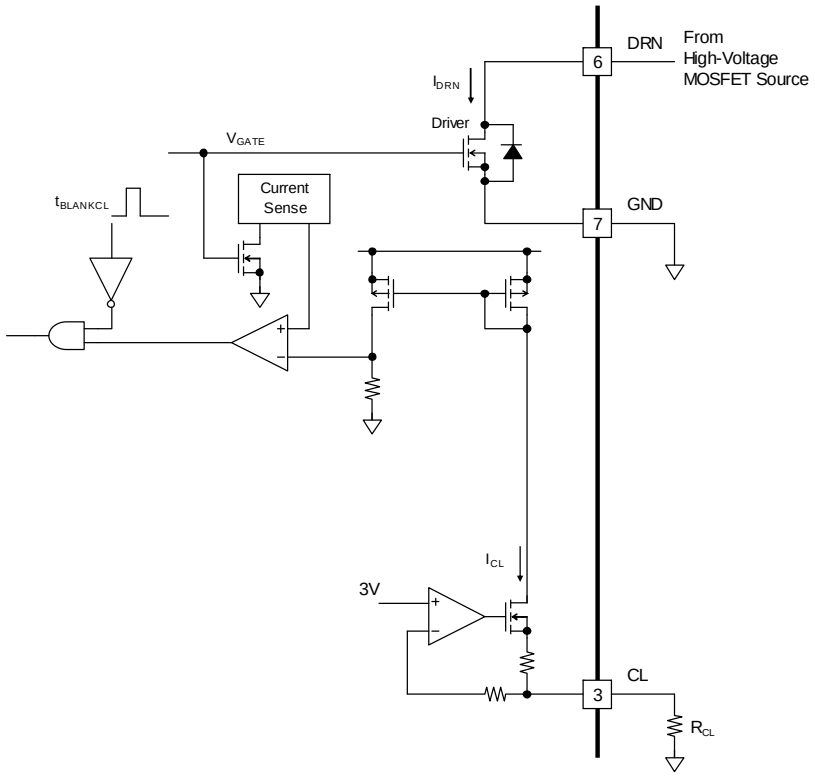
(7) CL Part

It is set the peak current of Primary Winding by connecting resistance with CL pin.
The maximum peak current of Primary Side is set by connecting resistance (R_{CL}) between the CL pin and GND.

$$I_{DRN(pk)} = \left(\frac{100kV}{R_{CL}}\right)$$

An about 400ns blanking time of the beginning of switching cycle is masking the spike noise. As a result, it prevents the sense of current from malfunctioning (See the figure below.).

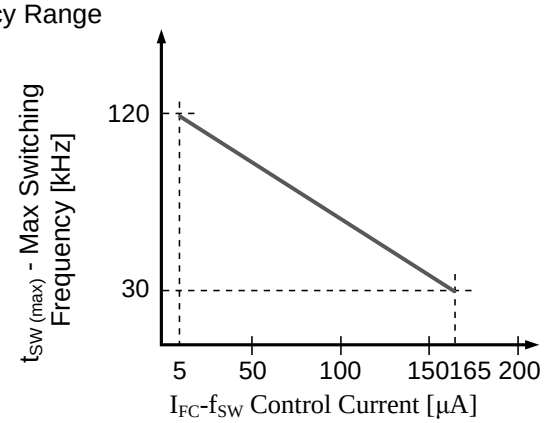
- Peak Current Control with CL pin



(8) FC Part

The switching frequency is controlled by setting the current of the FC pin. In on-time control, the switching frequency is set by pulling up the FC pin to VDD.
Switching frequency range is from 30kHz to 120kHz.

- Switching Frequency Range



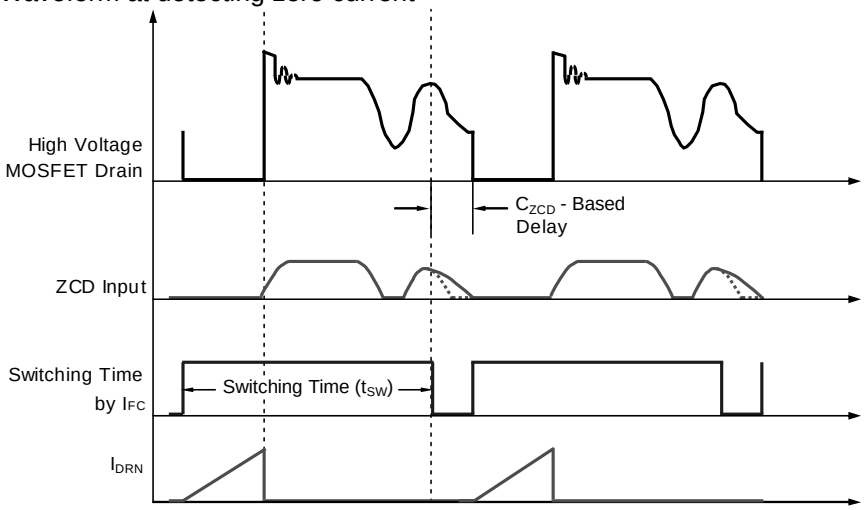
(9) ZCD Part

MB39C602 requires the following two conditions in order to start the next switching cycle.

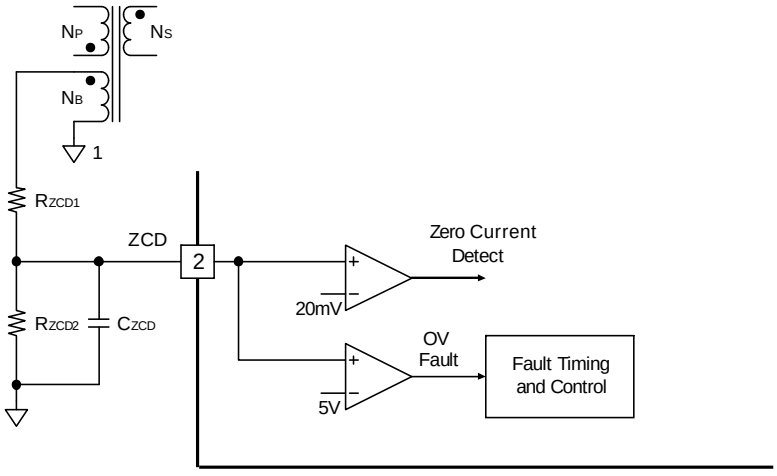
1. The time since the last turn-on edge must be equal to or longer than the switching time set by I_{FC}.
2. Immediately after zero current detection at ZCD pin. Or, the time since the last zero current detection must be longer than $t_{WAIT\ (ZCD)}$ (2.4µs or less).

The ZCD pin is connected with Auxiliary Winding of the transformer through the resistance division, and detects zero current as shown below.
A delay, 50ns to 200ns, can be added with C_{ZCD} to adjust the turn-on of the primary switch with the resonant bottom of Primarty Winding waveform.

- Switching Waveform at detecting zero current



- ZCD pin Connection



■ VARIOUS PROTECTION CIRCUITS

- Under voltage lockout protection (UVLO)

  The under voltage lockout protection (UVLO) protects IC from malfunction and protects the system from destruction/deterioration during the transient state and momentary drop due to start up for the power supply pin voltage (VDD). The voltage decrease of the VDD pin is detected with comparator, and output HS DRIVER is turned off and output DRIVER is turned off, and the switching is stopped. The system returns if the VDD pin becomes more than the threshold voltage of the UVLO circuit.

- Output over voltage Proteciton (OVP)

  When LED is in the state of open and the output voltage rises too much, the voltage of Auxiliary Winding and the voltage of the ZCD pin rise. The over voltage is detected by sampling this voltage of the ZCD pin. When ZCD pin voltage rises more than the threshold voltage of OVP, the over voltage is detected. Output HS DRIVER is turned off, and output DRIVER is turned off, and the switching is stopped. (latch-off)

  If the VDD pin becomes below the voltage of Fault Latch Reset, OVP is released.

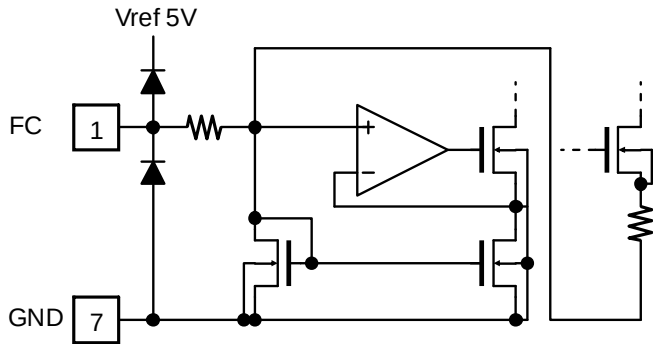
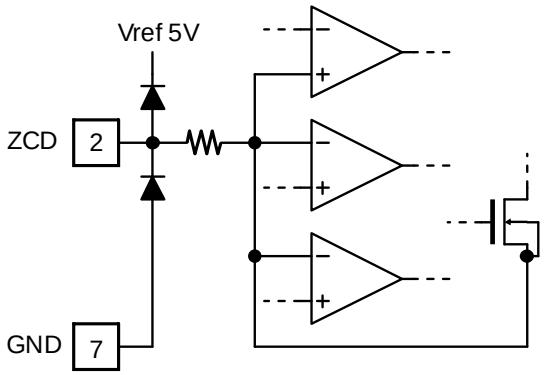
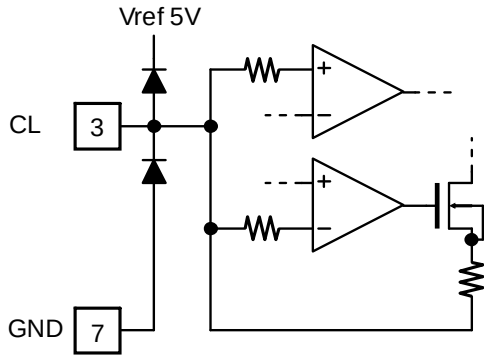
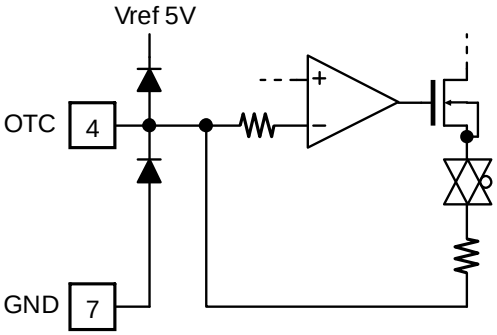
- Over temperature protection (OTP)

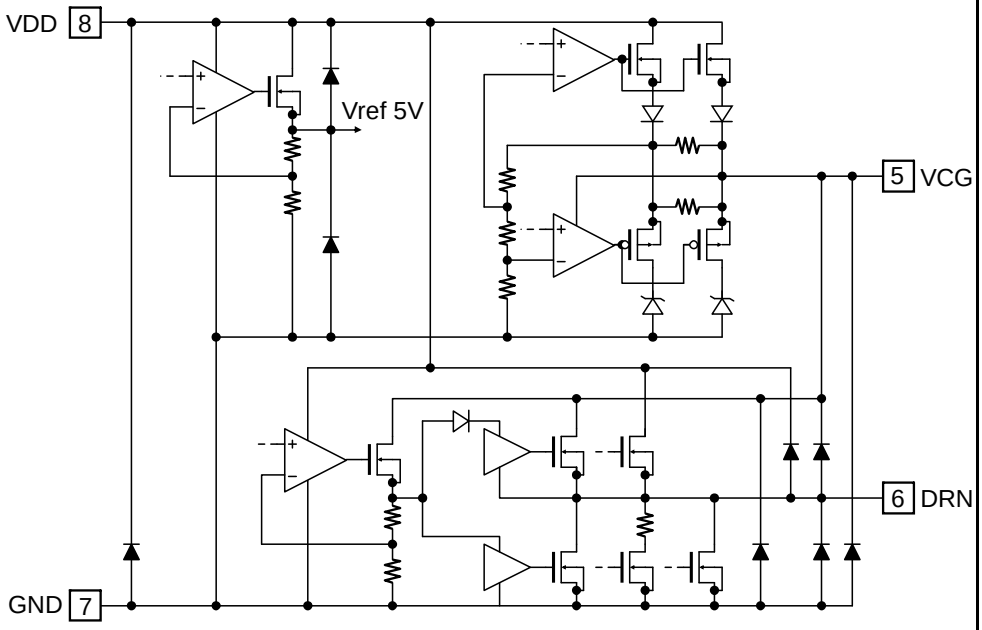
  The over temperature protection (OTP) is a function to protect IC from the thermal destruction. When the junction temperature reaches +150°C, output HS DRIVER is turn off, and output DRIVER is turned off, and the switching is stopped. It returns again when the junction temperature falls to +125°C (automatic recovery).

■ VARIOUS FUNCTION TABLES

Function	DRN				Detection Condition at Protected Operation	Return Condition	Remarks
	LS_DRV	HS_DRV	VDD SW	Discharge SW			
Normal Operation			OFF	OFF	-	-	-
Under Voltage Lockout Protection (UVLO)	OFF	OFF	ON	OFF	VDD < 8.0V	VDD > 10.2V	Standby
OTC Shutdown	OFF	OFF	ON	OFF	OTC = GND	OTC > 1V	Standby
Output Over Voltage Protection (OVP)	OFF	OFF	ON	ON	ZCD > 5V	VDD < 6V → VDD > 10.2V	Latch-off
Over Temperature Protection (OTP)	OFF	OFF	ON	OFF	Tj > +150°C	Tj < +125°C	-

■I/O PIN EQUIVALENT CIRCUIT SCHEMATIC

Pin No.	Pin Name	Equivalent Circuit Schematic
1	FC	
2	ZCD	
3	CL	
4	OTC	

Pin No.	Pin Name	Equivalent Circuit Schematic
5	VCG	
6	DRN	

■ USAGE PRECAUTION

1. **Do not configure the IC over the maximum ratings.**
   If the IC is used over the maximum ratings, the LSI may be permanently damaged.
   It is preferable for the device to normally operate within the recommended usage conditions. Usage outside of these conditions can have an adverse effect on the reliability of the LSI.

2. **Use the device within the recommended operating conditions.**
   The recommended values guarantee the normal LSI operation under the recommended operating conditions. The electrical ratings are guaranteed when the device is used within the recommended operating conditions and under the conditions stated for each item.

3. **Printed circuit board ground lines should be set up with consideration for common impedance.**

4. **Take appropriate measures against static electricity.**
   - Containers for semiconductor materials should have anti-static protection or be made of conductive material.
   - After mounting, printed circuit boards should be stored and shipped in conductive bags or containers.
   - Work platforms, tools, and instruments should be properly grounded.
   - Working personnel should be grounded with resistance of 250 kΩ to 1 MΩ in serial between body and ground.

5. **Do not apply negative voltages.**
   The use of negative voltages below - 0.3 V may make the parasitic transistor activated to the LSI, and can cause malfunctions.

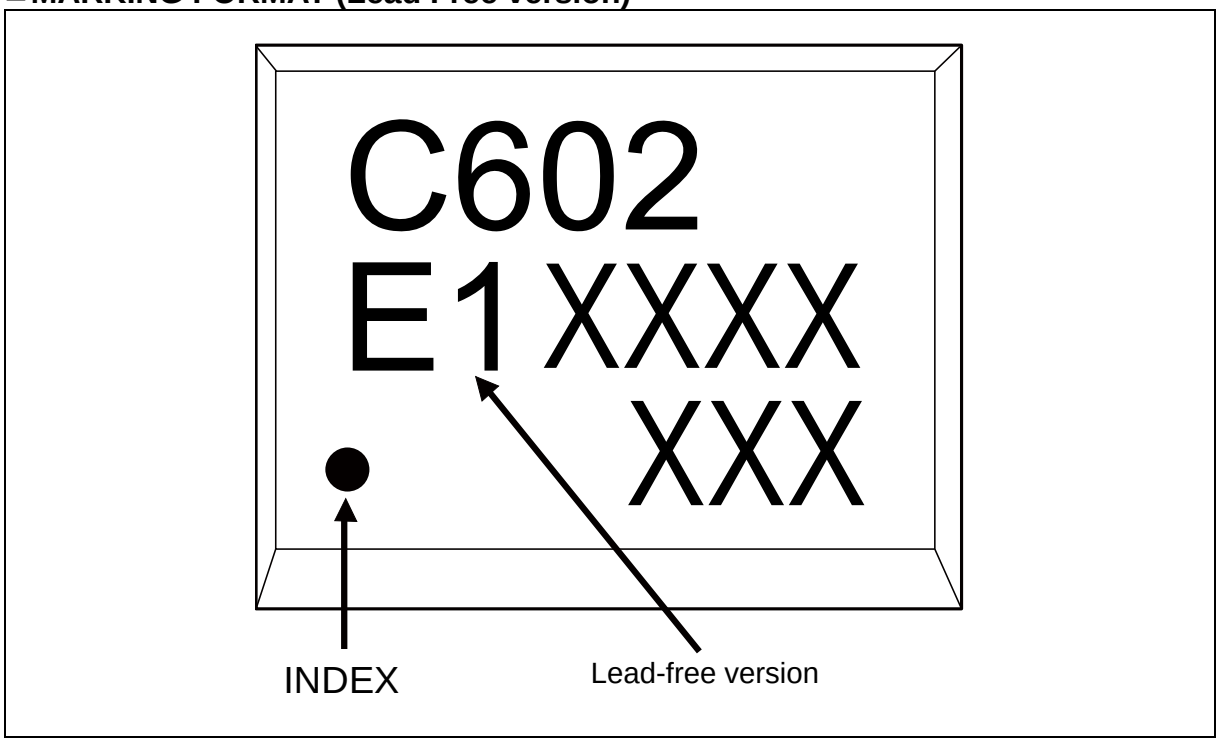
■ ORDERING INFORMATION

Part number	Package	Remarks
MB39C602PNF	8-pin plastic SOP (FPT-8P-M02)	

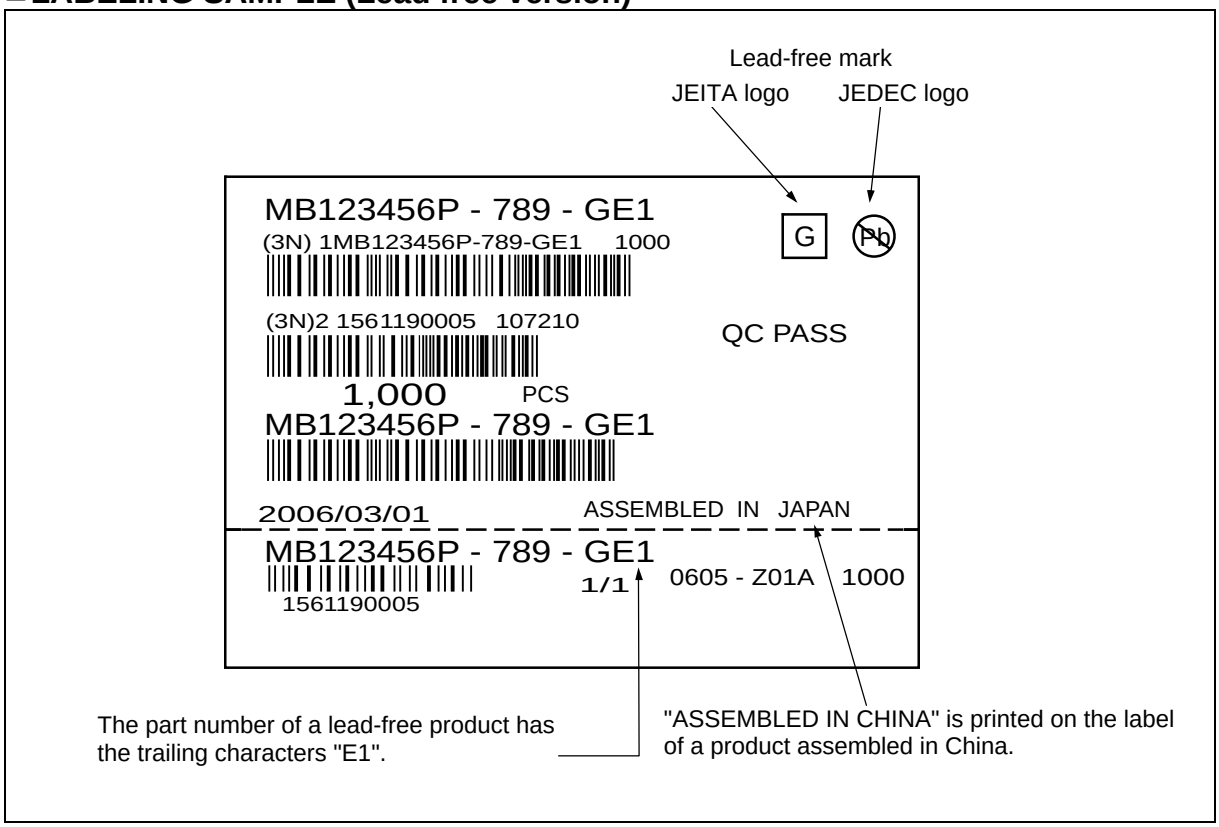
■ RoHS COMPLIANCE INFORMATION OF LEAD (Pb) FREE VERSION

The LSI products of FUJITSU SEMICONDUCTOR with “E1” are compliant with RoHS Directive, and has observed the standard of lead, cadmium, mercury, Hexavalent chromium, polybrominated biphenyls (PBB), and polybrominated diphenyl ethers (PBDE). A product whose part number has trailing characters “E1” is RoHS compliant.

■ MARKING FORMAT (Lead Free version)



■ LABELING SAMPLE (Lead free version)



■ MB39C602PNF RECOMMENDED CONDITIONS OF MOISTURE SENSITIVITY LEVEL

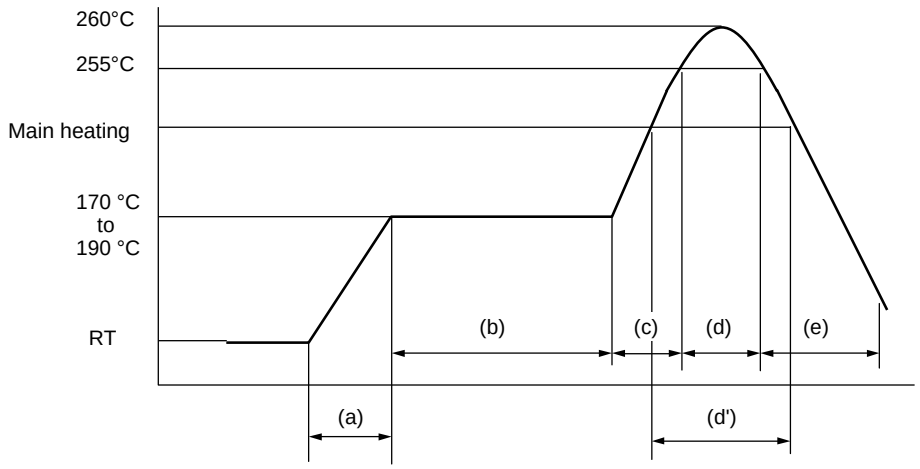
[FUJITSU SEMICONDUCTOR Recommended Mounting Conditions]

Recommended Reflow Condition

Item	Condition	
Mounting Method	IR (infrared reflow), warm air reflow	
Mounting times	2 times	
Storage period	Before opening	Please use it within two years after manufacture.
	From opening to the 2nd reflow	Less than 8 days
	When the storage period after opening was exceeded	Please process within 8 days after baking (125°C ±3°C, 24H+ 2H/─0H) . Baking can be performed up to two times.
Storage conditions	5°C to 30°C, 70% RH or less (the lowest possible humidity)	

[Mounting Conditions]

(1) Reflow Profile



"H" rank : 260°C Max

(a) Temperature Increase gradient	: Average 1°C/s to 4°C /s
(b) Preliminary heating	: Temperature 170°C to 190°C, 60 s to 180 s
(c) Temperature Increase gradient	: Average 1°C /s to 4°C /s
(d) Peak temperature	: Temperature 260°C Max; 255°C or more, 10 s or less
(d') Main Heating	: Temperature 230°C or more, 40 s or less or Temperature 225°C or more, 60 s or less or Temperature 220°C or more, 80 s or less
(e) Cooling	: Natural cooling or forced cooling

Note: Temperature : the top of the package bod

(2) JEDEC Condition: Moisture Sensitivity Level 3 (IPC/JEDEC J-STD-020D)

(3) Recommended manual soldering (partial heating method)

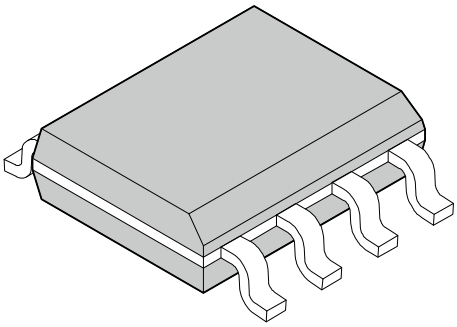
Item	Condition	
Storage period	Before opening	Within two years after manufacture
	Between opening and mounting	Within two years after manufacture (No need to control moisture during the storage period because of the partial heating method.)
Storage conditions	5°C to 30°C, 70% RH or less (the lowest possible humidity)	
Mounting conditions	Temperature at the tip of a soldering iron: 400°C Max Time: Five seconds or below per pin*	

*: Make sure that the tip of a soldering iron does not come in contact with the package body.

(4) Recommended dip soldering

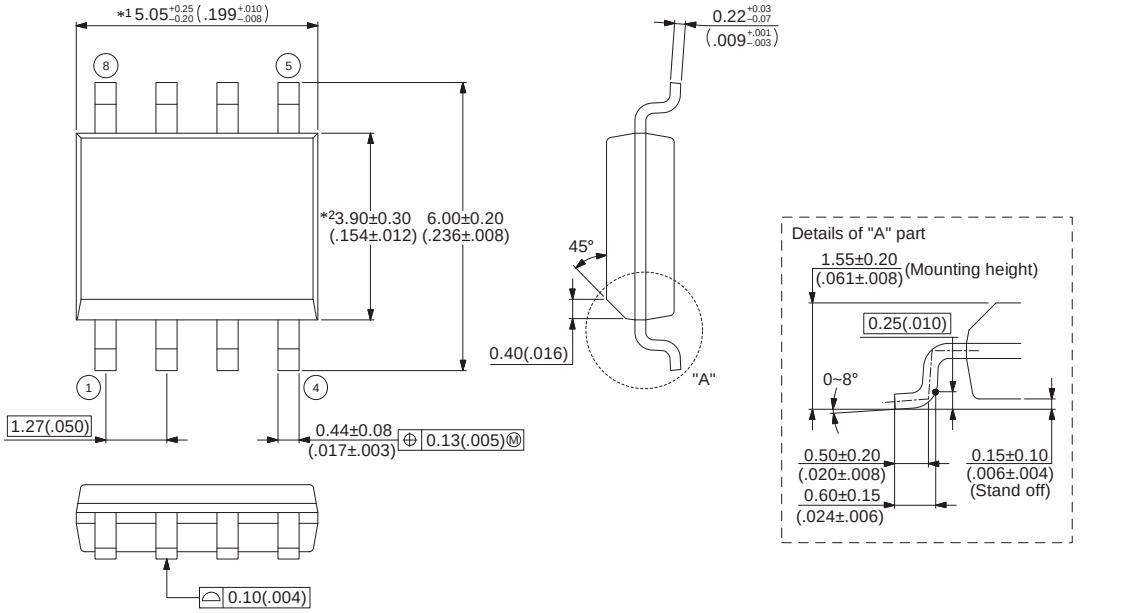
Item	Condition	
Mounting times	1 time	
Storage period	Before opening	Please use it within two years after manufacture.
	From opening and mounting	Less than 14 days
	When the storage period after opening was exceeded	Please process within 14 days after baking (125°C ±3°C, 24H+ 2H/−0H) . Baking can be performed up to two times.
Storage conditions	5°C to 30°C, 70% RH or less (the lowest possible humidity)	
Mounting condition	Temperature at soldering tub: 260°C Max Time: Five seconds or below	

■ PACKAGE DIMENSIONS

8-pin plastic SOP		
	Lead pitch	1.27 mm
	Package width× package length	3.9 mm × 5.05 mm
	Lead shape	Gullwing
	Sealing method	Plastic mold
	Mounting height	1.75 mm MAX
	Weight	0.06 g
(FPT-8P-M02)		

8-pin plastic SOP
(FPT-8P-M02)

Note 1) *1 : These dimensions include resin protrusion.
Note 2) *2 : These dimensions do not include resin protrusion.
Note 3) Pins width and pins thickness include plating thickness.
Note 4) Pins width do not include tie bar cutting remainder.



Dimensions in mm (inches).
Note: The values in parentheses are reference values.

Please check the latest package dimension at the following URL.
http://edevice.fujitsu.com/package/en-search/

MEMO

MEMO

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